

FEATURES

- Available in the Texas Instruments NanoFree™ Package
- Control Inputs VIH/VIL Levels Are Referenced to V_{CCA} Voltage
- Fully Configurable Dual-Rail Design Allows Each Port to Operate Over the Full 1.2-V to 3.6-V Power-Supply Range
- I/Os Are 4.6-V Tolerant
- I_{off} Supports Partial Power-Down-Mode Operation
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Max Data Rates
 - 500 Mbps (1.8-V to 3.3-V Translation)
 - 320 Mbps (<1.8-V to 3.3-V Translation)
 - 320 Mbps (Translate to 2.5 V or 1.8 V)
 - 280 Mbps (Translate to 1.5 V)
 - 240 Mbps (Translate to 1.2 V)
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

DESCRIPTION/ORDERING INFORMATION

This dual-bit noninverting bus transceiver uses two separate configurable power-supply rails. The SN74AVCH2T45 is optimized to operate with V_{CCA}/V_{CCB} set at 1.4 V to 3.6 V. It is operational with V_{CCA}/V_{CCB} as low as 1.2 V. The A port is designed to track V_{CCA} . V_{CCA} accepts any supply voltage from 1.2 V to 3.6 V. The B port is designed to track V_{CCB} . V_{CCB} and supply voltage from 1.2 V to 3.6 V. This allows for universal low-voltage bidirectional translation between any of the 1.2-V, 1.5-V, 1.8-V, 2.5-V, and 3.3-V voltage nodes.

ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽³⁾
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74AVCH2T45YZPR	TF_
–40°C to 85°C	SSOP – DCT	Reel of 3000	SN74AVCH2T45DCTR	ET2
	VSSOP – DCU	Reel of 3000	SN74AVCH2T45DCUR	ET2_

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI (2)website at www.ti.com.

(3) DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site. DCU: The actual top-side marking has one additional character that designates the assembly/test site. YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. NanoFree is a trademark of Texas Instruments.

(TOP VIEW)	
V _{CCA} 1 8] V _{CCB}
A1 2 7] B1
A2 3 6] B2
GND 4 5] DIR

DCT OR DCU PACKAGE

YZP PACKAGE (BOTTOM VIEW)

GND	D 4	5 💿	DIR
A2	© 3	6©	B2
A1	®1) 2	7 B2	B1
A2 A1 V _{CCA}	A1) 1	8 @2	V _{CCB}



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DESCRIPTION/ORDERING INFORMATION (CONTINUED)

The SN74AVCH2T45 is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input.

The SN74AVCH2T45 is designed so that the DIR input is powered by V_{CCA}.

This device is fully specified for partial-power-down applications using Ioff. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The V_{CC} isolation feature ensures that if either V_{CC} input is at GND, then both outputs are in the high-impedance state. The bus-hold circuitry on the powered-up side always stays active.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

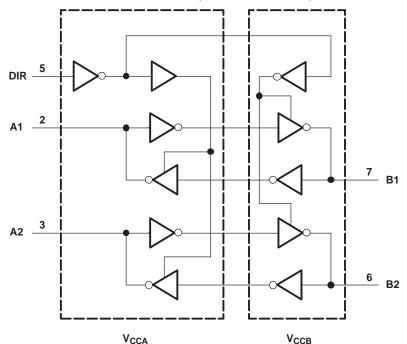
NanoFree[™] package technology is a major breakthrough in IC packaging concepts, using the die as the package.

FUNCTION TABLE⁽¹⁾ (each transceiver)

INPUT DIR	OPERATION
L	B data to A bus
Н	A data to B bus

Input circuits of the data I/Os (1) always are active.

LOGIC DIAGRAM (POSITIVE LOGIC)⁽¹⁾



(1) Pin numbers shown are for the DCT and DCU packages.



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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CCA} V _{CCB}	Supply voltage range		-0.5	4.6	V
		I/O ports (A port)	-0.5	4.6	
VI	Input voltage range ⁽²⁾	I/O ports (B port)	-0.5	4.6	V
		Control inputs	-0.5	4.6	
V	Voltage range applied to any output	A port	-0.5	4.6	V
Vo	in the high-impedance or power-off state ⁽²⁾	B port	-0.5	4.6	v
V	Valtage range emplied to enviouting the high or law state $\binom{2}{3}$	A port	-0.5	V _{CCA} + 0.5	V
Vo	Voltage range applied to any output in the high or low state $^{(2)}$	B port	-0.5	V _{CCB} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
lo	Continuous output current			±50	mA
	Continuous current through V _{CCA} , V _{CCB} , or GND			±100	mA
		DCT package		220	
θ_{JA}	Package thermal impedance ⁽⁴⁾	DCU package		227	°C/W
		YZP package		102	
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input voltage and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The output positive-voltage rating may be exceeded up to 4.6 V maximum if the output current rating is observed.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

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Recommended Operating Conditions⁽¹⁾⁽²⁾⁽³⁾

			V _{CCI}	V _{cco}	MIN	MAX	UNIT
V _{CCA}	Supply voltage				1.2	3.6	V
V _{CCB}	Supply voltage				1.2	3.6	V
			1.2 V to 1.95 V		$V_{CC}\ \times 0.65$		
VIH	High-level input voltage	Data inputs ⁽⁴⁾	1.95 V to 2.7 V		1.6		V
	input voltage		2.7 V to 3.6 V		2		
			1.2 V to 1.95 V			$V_{CCI}\ \times 0.35$	
V _{IL}	Low-level input voltage	Data inputs ⁽⁴⁾	1.95 V to 2.7 V			0.7	V
	input voltage		2.7 V to 3.6 V			0.8	
			1.2 V to 1.95 V		$V_{CCA} imes 0.65$		
VIH	High-level input voltage	DIR (referenced to V _{CCA}) ⁽⁵⁾	1.95 V to 2.7 V		1.6		V
	input voltage		2.7 V to 3.6 V		2		
			1.2 V to 1.95 V			$V_{CCA}\ \times 0.35$	
V _{IL}	Low-level input voltage	DIR (referenced to V _{CCA}) ⁽⁵⁾	1.95 V to 2.7 V			0.7	V
	input voltage		2.7 V to 3.6 V			0.8	
VI	Input voltage				0	3.6	V
		Active state			0	V _{CCO}	V
Vo	Output voltage	3-state			0	3.6	v
				1.2 V		-3	
				1.4 V to 1.6 V		-6	
l _{он}	High-level output cu	rrent		1.65 V to 1.95 V		-8	mA
				2.3 V to 2.7 V		-9	
				3 V to 3.6 V		-12	
				1.2 V		3	
				1.4 V to 1.6 V		6	
lol	Low-level output cur	rent		1.65 V to 1.95 V		8	mA
				2.3 V to 2.7 V		9	
				3 V to 3.6 V		12	
Δt/Δv	Input transition rise	or fall rate				5	ns/V
T _A	Operating free-air te	mperature			-40	85	°C

V_{CCI} is the V_{CC} associated with the input port.
 V_{CCO} is the V_{CC} associated with the output port.
 All unused data inputs of the device must be held at V_{CCI} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.
 For V_{CCI} values not specified in the data sheet, V_{IH} min = V_{CCI} × 0.7 V, V_{IL} max = V_{CCI} × 0.3 V.
 For V_{CCA} values not specified in the data sheet, V_{IH} min = V_{CCA} × 0.7 V, V_{IL} max = V_{CCA} × 0.3 V.



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Electrical Characteristics⁽¹⁾⁽²⁾

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDI		v	v	T _A = 2	25°C		–40°C to 85	5°C	UNIT	
PARAMETER	TEST CONDI	TIONS	V _{CCA}	V _{CCB}	MIN 1	ГҮР	MAX	MIN	MAX	UNIT	
	I _{OH} = -100 μA		1.2 V to 3.6 V	1.2 V to 3.6 V				$V_{CCO} - 0.2$			
	$I_{OH} = -3 \text{ mA}$		1.2 V	1.2 V	(0.95					
	I _{OH} = -6 mA		1.4 V	1.4 V				1.05			
V _{OH}	I _{OH} = -8 mA	$V_{I} = V_{IH}$	1.65 V	1.65 V				1.2		V	
	I _{OH} = -9 mA		2.3 V	2.3 V				1.75			
	I _{OH} = -12 mA		3 V	3 V				2.3			
	I _{OL} = 100 μA		1.2 V to 3.6 V	1.2 V to 3.6 V					0.2		
	I _{OL} = 3 mA		1.2 V	1.2 V	(0.15					
	I _{OL} = 6 mA	., .,	1.4 V	1.4 V					0.35	. /	
V _{OL}	I _{OL} = 8 mA	$V_{I} = V_{IL}$	1.65 V	1.65 V					0.45	V	
	I _{OL} = 9 mA		2.3 V	2.3 V					0.55		
	I _{OL} = 12 mA		3 V	3 V					0.7		
II DIR input	$V_I = V_{CCA}$ or GN	D	1.2 V to 3.6 V	1.2 V to 3.6 V	±0.	025	±0.25		±1	μA	
	V _I = 0.42 V		1.2 V	1.2 V		25					
	$V_{I} = 0.49 V$ $V_{I} = 0.58 V$ $V_{I} = 0.7 V$		1.4 V	1.4 V				15		μΑ	
I _{BHL} ⁽³⁾			1.65 V	1.65 V				25			
2.12			2.3 V	2.3 V				45			
	$V_1 = 0.8 V$			3.3 V				100			
	V ₁ = 0.78 V		1.2 V	1.2 V		-25					
	V _I = 0.91 V		1.4 V	1.4 V				–15			
I _{BHH} ⁽⁴⁾	V _I = 1.07 V		1.65 V	1.65 V				-25		μA	
2	V _I = 1.6 V		2.3 V	2.3 V				-45		·	
	V ₁ = 2 V		3.3 V	3.3 V				-100			
	-		1.2 V	1.2 V		50					
			1.6 V	1.6 V				125			
I _{BHLO} ⁽⁵⁾	$V_{I} = 0$ to V_{CC}		1.95 V	1.95 V				200		μA	
220			2.7 V	2.7 V				300		•	
			3.6 V	3.6 V				500			
			1.2 V	1.2 V		-50					
			1.6 V	1.6 V				-125			
I _{BHHO} ⁽⁶⁾	$V_{I} = 0$ to V_{CC}		1.95 V	1.95 V				-200		μA	
	$v_1 = 0$ to v_{CC}		2.7 V	2.7 V				-300		μA	
			3.6 V	3.6 V				-500			

(1) V_{CCI} is the V_{CC} associated with the input port.

(2) V_{CCO} is the V_{CC} associated with the output port.

(3) The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL} max.

(4) The bus-hold circuit can source at least the minimum high sustaining current at V_{IH} min. I_{BHH} should be measured after raising V_{IN} to V_{CC} and then lowering it to V_{IH} min.

(5) An external driver must source at least I_{BHLO} to switch this node from low to high.

(6) An external driver must sink at least I_{BHHO} to switch this node from high to low.



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Electrical Characteristics (continued)⁽¹⁾⁽²⁾

over recommended operating free-air temperature range (unless otherwise noted)

БА	RAMETER	TEST CONDITI	ONE	М	М	TA	∖ = 25°	С	–40°C to	85°C	UNIT
FA	RANIEIER	TEST CONDITI	UNS	V _{CCA}	V _{CCB}	MIN	TYP	MAX	MIN	MAX	UNIT
	A port	$V_{\rm I}$ or $V_{\rm O} = 0$ to 3.6 V		0 V	0 V to 3.6 V		±0.1	±1		±5	۸
I _{off}	B port			0 V to 3.6 V	0 V		±0.1	±1		±5	μA
	B port	$V_{O} = V_{CCO}$ or GND,		0 V	3.6 V		±0.5	±2.5		±5	۸
I _{OZ}	A port	$V_{I} = V_{CCI}$ or GND		3.6 V	0 V		±0.5	±2.5		±5	μA
				1.2 V to 3.6 V	1.2 V to 3.6 V					10	
I_{CCA}		$V_I = V_{CCI}$ or GND,	$V_{I} = V_{CCI} \text{ or } GND, \qquad I_{O} = 0$		3.6 V					-2	μA
				3.6 V	0 V					10	
				1.2 V to 3.6 V	1.2 V to 3.6 V					10	
I _{CCB}		$V_I = V_{CCI}$ or GND,	$I_{O} = 0$	0 V	3.6 V					10	μΑ
				3.6 V	0 V					-2	
I _{CCA} +	- I _{CCB}	$V_{I} = V_{CCI}$ or GND,	$I_{O} = 0$	1.2 V to 3.6 V	1.2 V to 3.6 V					20	μΑ
Ci	Control inputs	V ₁ = 3.3 V or GND		3.3 V	3.3 V		2.5				pF
Cio	A or B port	$V_0 = 3.3 \text{ V or GND}$		3.3 V	3.3 V		6				pF

 $\begin{array}{ll} \mbox{(1)} & V_{CCO} \mbox{ is the } V_{CC} \mbox{ associated with the output port.} \\ \mbox{(2)} & V_{CCI} \mbox{ is the } V_{CC} \mbox{ associated with the input port.} \end{array}$

Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 1.2 V$ (see Figure 11)

PARAMETER	FROM	то	V _{CCB} = 1.2 V	V _{CCB} = 1.5 V	V _{CCB} = 1.8 V	V _{CCB} = 2.5 V	V _{CCB} = 3.3 V	UNIT
PARAMETER	(INPUT)	(OUTPUT)	ТҮР	ТҮР	ТҮР	ТҮР	ТҮР	UNIT
t _{PLH}	٨	P	3.1	2.6	2.4	2.2	2.2	
t _{PHL}	A	В	3.1	2.6	2.4	2.2	2.2	ns
t _{PLH}	В	^	3.4	3.1	3	2.9	2.9	
t _{PHL}	D	A	3.4	3.1	3	2.9	2.9	ns
t _{PHZ}	DIR	А	5.2	5.2	5.1	5	4.8	
t _{PLZ}	DIR	A	5.2	5.2	5.1	5	4.8	ns
t _{PHZ}		P	5	4	3.8	2.8	3.2	
t _{PLZ}	DIR	В	5	4	3.8	2.8	3.2	ns
t _{PZH} ⁽¹⁾			8.4	7.1	6.8	5.7	6.1	
t _{PZL} ⁽¹⁾	DIR	A	8.4	7.1	6.8	5.7	6.1	ns
t _{PZH} ⁽¹⁾			8.3	7.8	7.5	7.2	7	
t _{PZL} ⁽¹⁾	DIR	В	8.3	7.8	7.5	7.2	7	ns

(1) The enable time is a calculated value derived using the formula shown in the enable times section.

Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$ (see Figure 11)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.2 V	V _{CCB} = ± 0.1		V _{ССВ} = ± 0.1		V _{ССВ} = ± 0.2		V _{ССВ} = ± 0.		UNIT
	(INFOT)	(001901)	ТҮР	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	А	В	2.8	0.7	5.4	0.5	4.6	0.4	3.7	0.3	3.5	
t _{PHL}	A	Б	2.8	0.7	5.4	0.5	4.6	0.4	3.7	0.3	3.5	ns
t _{PLH}	В	А	2.7	0.8	5.4	0.7	5.2	0.6	4.9	0.5	4.7	
t _{PHL}	D	A	2.7	0.8	5.4	0.7	5.2	0.6	4.9	0.5	4.7	ns
t _{PHZ}	DIR	•	3.9	1.3	8.5	1.3	7.8	1.1	7.7	1.4	7.6	
t _{PLZ}	DIR	A	3.9	1.3	8.5	1.3	7.8	1.1	7.7	1.4	7.6	ns
t _{PHZ}	חוח	В	4.7	1.1	7	1.4	6.9	1.2	6.9	1.7	7.1	
t _{PLZ}	DIR	Б	4.7	1.1	7	1.4	6.9	1.2	6.9	1.7	7.1	ns
t _{PZH} ⁽¹⁾	חוח	٨	7.4		12.4		12.1		11.8		11.8	
t _{PZL} ⁽¹⁾	DIR	A —	7.4		12.4		12.1		11.8		11.8	ns
t _{PZH} ⁽¹⁾	סוס	P	6.7		13.9		12.4		11.4		11.1	
t _{PZL} ⁽¹⁾	DIR	В	6.7		13.9		12.4		11.4		11.1	ns

(1) The enable time is a calculated value derived using the formula shown in the enable times section.

Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (see Figure 11)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.2 V	V _{CCB} = ± 0.1		V _{CCB} = ± 0.7	= 1.8 V 15 V	V _{CCB} = ± 0.2		V _{CCB} = ± 0.3		UNIT		
	(INFOT)	(001201)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX			
t _{PLH}	А	В	2.7	0.5	5.2	0.4	4.3	0.2	3.4	0.2	3.1	ns		
t _{PHL}	A	D	2.7	0.5	5.2	0.4	4.3	0.2	3.4	0.2	3.1	115		
t _{PLH}	В	А	2.4	0.7	4.7	0.5	4.4	0.5	4	0.4	3.8	20		
t _{PHL}	Б	A	2.4	0.7	4.7	0.5	4.4	0.5	4	0.4	3.8	ns		
t _{PHZ}	DIR	А	3.7	1.3	8.1	0.7	6.9	1.4	5.3	1.1	5.2	20		
t _{PLZ}	DIK	A	3.7	1.3	8.1	0.7	6.9	1.4	5.3	1.1	5.2	ns		
t _{PHZ}	DIR	В	4.4	1.3	5.8	1.3	5.9	0.8	5.7	1.5	5.9	20		
t _{PLZ}	DIK	D	4.4	1.3	5.8	1.3	5.9	0.8	5.7	1.5	5.9	ns		
t _{PZH} ⁽¹⁾	DIR	^	6.8		10.5		10.3		9.7		9.7	20		
t _{PZL} ⁽¹⁾	DIK	A	A	A	6.8		10.5		10.3		9.7		9.7	ns
t _{PZH} ⁽¹⁾	DIR	В	6.4		13.3		11.2		8.7		8.3	20		
t _{PZL} ⁽¹⁾	DIR	D	6.4		13.3		11.2		8.7		8.3	ns		

(1) The enable time is a calculated value derived using the formula shown in the enable times section.



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Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (see Figure 11)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.2 V	V _{CCB} = ± 0.1		V _{CCB} = ± 0.1		V _{CCB} = ± 0.2		V _{CCB} = ± 0.3		UNIT			
	(INFOT)	(001F01)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX				
t _{PLH}	А	В	2.6	0.4	4.9	0.2	4	0.2	3	0.2	2.6	20			
t _{PHL}	A	Б	2.6	0.4	4.9	0.2	4	0.2	3	0.2	2.6	ns			
t _{PLH}	В	А	2.1	0.6	3.8	0.5	3.4	0.4	3	0.3	2.8	ns			
t _{PHL}	Б	A	2.1	0.6	3.8	0.5	3.4	0.4	3	0.3	2.8	115			
t _{PHZ}	DIR	А	2.4	0.7	7.9	0.8	6.4	0.8	5	0.5	4.3	20			
t _{PLZ}	DIR	A	2.4	0.7	7.9	0.8	6.4	0.8	5	0.5	4.3	ns			
t _{PHZ}	DIR	В	3.8	1	4.3	0.6	4.3	0.5	4.2	1.1	4.1	20			
t _{PLZ}	DIR	Б	3.8	1	4.3	0.6	4.3	0.5	4.2	1.1	4.1	ns			
t _{PZH} ⁽¹⁾	DIR	^	5.9		8.5		7.7		7.2		6.9				
t _{PZL} ⁽¹⁾	DIK	A	A	A	A	5.9		8.5		7.7		7.2		6.9	ns
t _{PZH} ⁽¹⁾	סוס	Р	5		12.8		10.4		8		6.9	~~			
t _{PZL} ⁽¹⁾	DIR	В	5		12.8		10.4		8		6.9	ns			

(1) The enable time is a calculated value derived using the formula shown in the *enable times* section.

Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (see Figure 11)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.2 V	V _{CCB} = 1.5 V ± 0.1 V		V _{CCB} = 1.8 V ± 0.15 V		V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		UNIT	
	(INFUT)	(001201)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
t _{PLH}	А	В	2.5	0.3	4.7	0.2	3.8	0.2	2.8	0.2	2.4	20	
t _{PHL}	A	Б	2.5	0.3	4.7	0.2	3.8	0.2	2.8	0.2	2.4	ns	
t _{PLH}	5	А	2.1	0.6	3.6	0.4	3.1	0.3	2.6	0.3	2.4	20	
t _{PHL}	В	A	2.1	0.6	3.6	0.4	3.1	0.3	2.6	0.3	2.4	ns	
t _{PHZ}	DIR	А	2.9	1.1	8	1	6.5	1.3	4.7	1.2	4	20	
t _{PLZ}	DIK	A	2.9	1.1	8	1	6.5	1.3	4.7	1.2	4	ns	
t _{PHZ}	DIR	В	3.4	0.5	6.6	0.3	5.6	0.3	4.6	1.1	4.2	20	
t _{PLZ}	DIR	D	3.4	0.5	6.6	0.3	5.6	0.3	4.6	1.1	4.2	ns	
t _{PZH} ⁽¹⁾	DIR	А	5.5		10.2		8.7		7.2		6.6	20	
t _{PZL} ⁽¹⁾	DIR	A	5.5		10.2		8.7		7.2		6.6	ns	
t _{PZH} ⁽¹⁾	DIR	5		5.4		12.7		10.3		7.5		6.4	20
t _{PZL} ⁽¹⁾	DIK	В	5.4		12.7		10.3		7.5		6.4	ns	

(1) The enable time is a calculated value derived using the formula shown in the enable times section.

Operating Characteristics

 $T_A = 25^{\circ}C$

P	ARAMETER	TEST CONDITIONS	V _{CCA} = V _{CCB} = 1.2 V	V _{CCA} = V _{CCB} = 1.5 V	V _{CCA} = V _{CCB} = 1.8 V	V _{CCA} = V _{CCB} = 2.5 V	V _{CCA} = V _{CCB} = 3.3 V	UNIT
		CONDITIONO	TYP	TYP	TYP	TYP	TYP	
C _{pdA} ⁽¹⁾	A-port input, B-port output	$C_{L} = 0,$	3	3	3	3	4	۲
CpdA	B-port input, A-port output	f = 10 MHz, $t_r = t_f = 1 \text{ ns}$	13	13	14	15	15	pF
C (1)	A-port input, B-port output	C _L = 0, f = 10 MHz,	13	13	14	15	15	pF
C _{pdB} ⁽¹⁾ B-port input, A-port output		$t_r = t_f = 1 \text{ ns}$	3	3	3	3	4	рг

(1) Power dissipation capacitance per transceiver

POWER-UP CONSIDERATIONS

A proper power-up sequence always should be followed to avoid excessive supply current, bus contention, oscillations, or other anomalies. To guard against such power-up problems, take the following precautions:

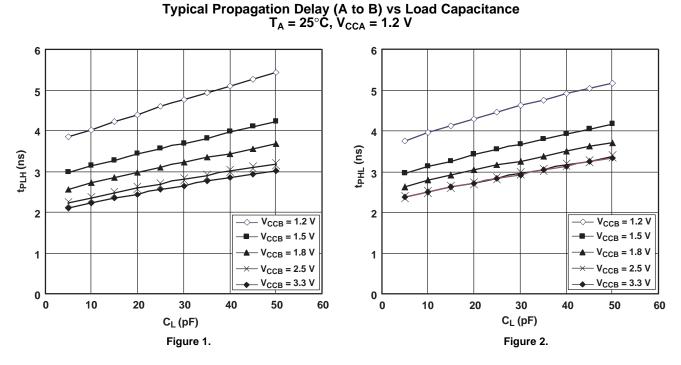
- 1. Connect ground before any supply voltage is applied.
- 2. Power up V_{CCA} .
- 3. V_{CCB} can be ramped up along with or after V_{CCA} .

V	V _{CCA}									
V _{CCB}	0 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	UNIT			
0 V	0	<0.5	<0.5	<0.5	<0.5	<0.5				
1.2 V	<0.5	<1	<1	<1	<1	1				
1.5 V	<0.5	<1	<1	<1	<1	1				
1.8 V	<0.5	<1	<1	<1	<1	<1	μA			
2.5 V	<0.5	1	<1	<1	<1	<1				
3.3 V	<0.5	1	<1	<1	<1	<1				

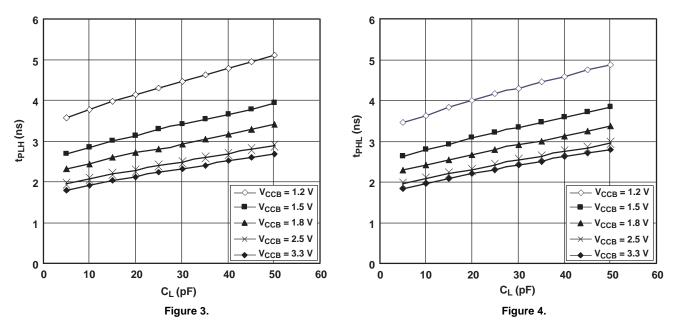
Table 1. Typical Total Static Power Consumption (I_{CCA} + I_{CCB})



TYPICAL CHARACTERISTICS



Typical Propagation Delay (A to B) vs Load Capacitance T_{A} = 25°C, V_{CCA} = 1.5 V

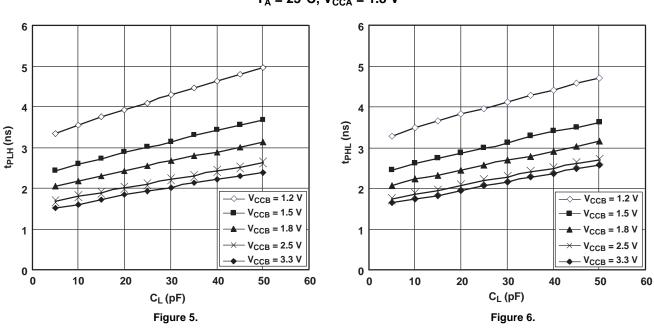


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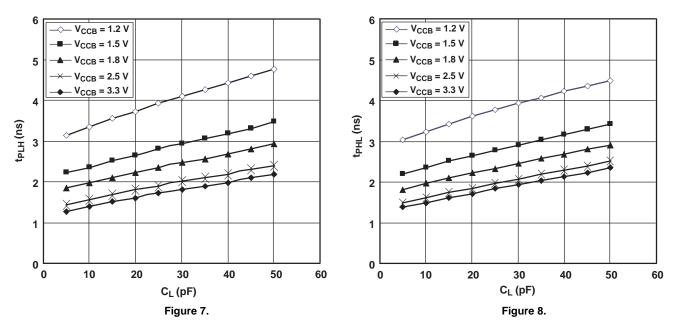
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TYPICAL CHARACTERISTICS (continued)



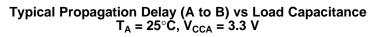
Typical Propagation Delay (A to B) vs Load Capacitance T_{A} = 25°C, V_{CCA} = 1.8 V

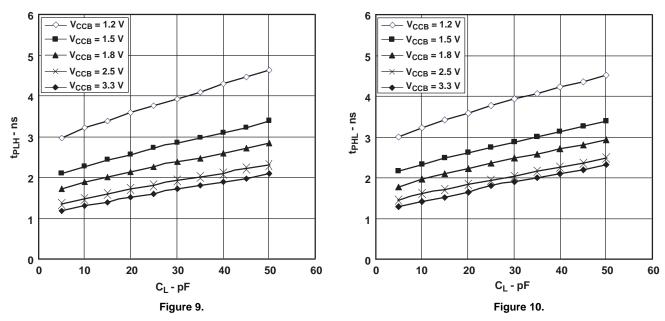
Typical Propagation Delay (A to B) vs Load Capacitance T_{A} = 25°C, V_{CCA} = 2.5 V





TYPICAL CHARACTERISTICS (continued)

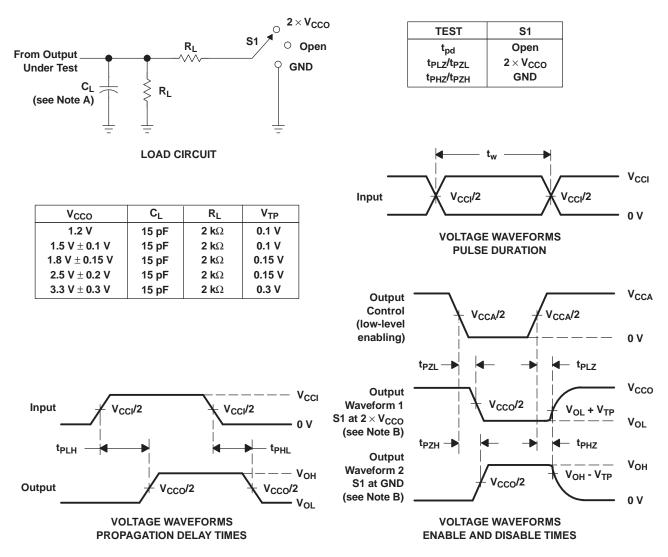




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PARAMETER MEASUREMENT INFORMATION

NOTES: A. C_{L} includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , dv/dt \geq 1 V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. V_{CCI} is the V_{CC} associated with the input port.
- I. V_{CCO} is the V_{CC} associated with the output port.

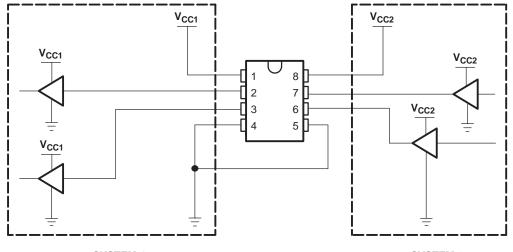
Figure 11. Load Circuit and Voltage Waveforms



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APPLICATION INFORMATION

Figure 12 is an example of the SN74AVCH2T45 circuit used in a unidirectional logic level-shifting application.



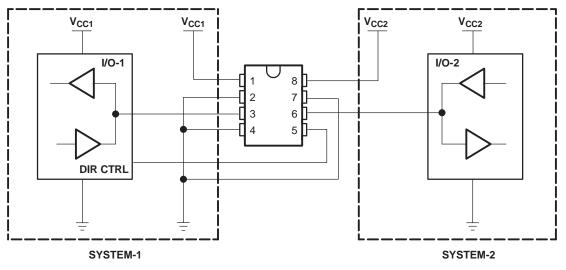
SYSTEM-1

SYSTEM-2

Figure 12. Bidirectional Logic Level-Shifting Application

PIN	NAME	FUNCTION	DESCRIPTION
1	V _{CCA}	V _{CC1}	SYSTEM-1 supply voltage (1.2 V to 3.6 V)
2	A1	OUT1	Output level depends on V _{CC1} voltage.
3	A2	OUT2	Output level depends on V _{CC1} voltage.
4	GND	GND	Device GND
5	DIR	DIR	GND (low level) determines B-port to A-port direction.
6	B2	IN2	Input threshold value depends on V _{CC2} voltage.
7	B1	IN1	Input threshold value depends on V _{CC2} voltage.
8	V _{CCB}	V _{CC2}	SYSTEM-2 supply voltage (1.2 V to 3.6 V)

Figure 13 shows the SN74AVCH2T45 used in a bidirectional logic level-shifting application. Since the SN74AVCH2T45 does not have an output-enable (OE) pin, system designers should take precautions to avoid bus contention between SYSTEM-1 and SYSTEM-2 when changing directions.





Following is a sequence that shows data transmission from SYSTEM-1 to SYSTEM-2 and then from SYSTEM-2 to SYSTEM-1.

STATE	DIR CTRL	I/O-1	I/O-2	DESCRIPTION
1	Н	Out	In	SYSTEM-1 data to SYSTEM-2
2	Н	Hi-Z	Hi-Z	SYSTEM-2 is getting ready to send data to SYSTEM-1. I/O-1 and I/O-2 are disabled. The bus-line state depends on bus hold.
3	L	Hi-Z	Hi-Z	DIR bit is flipped. I/O-1 and I/O-2 still are disabled. The bus-line state depends on bus hold.
4	L	In	Out	SYSTEM-2 data to SYSTEM-1

Enable Times

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Calculate the enable times for the SN74AVCH2T45 using the following formulas:

- t_{PZH} (DIR to A) = t_{PLZ} (DIR to B) + t_{PLH} (B to A)
- t_{PZL} (DIR to A) = t_{PHZ} (DIR to B) + t_{PHL} (B to A)
- t_{PZH} (DIR to B) = t_{PLZ} (DIR to A) + t_{PLH} (A to B)
- t_{PZL} (DIR to B) = t_{PHZ} (DIR to A) + t_{PHL} (A to B)

In a bidirectional application, these enable times provide the maximum delay from the time the DIR bit is switched until an output is expected. For example, if the SN74AVCH2T45 initially is transmitting from A to B, the DIR bit is switched; the B port of the device must be disabled before presenting it with an input. After the B port has been disabled, an input signal applied to it appears on the corresponding A port after the specified propagation delay.



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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
74AVCH2T45DCTRE4	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
74AVCH2T45DCTRG4	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
74AVCH2T45DCTTE4	ACTIVE	SM8	DCT	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
74AVCH2T45DCURE4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
74AVCH2T45DCURG4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
74AVCH2T45DCUTE4	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
74AVCH2T45DCUTG4	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74AVCH2T45DCTR	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74AVCH2T45DCTT	ACTIVE	SM8	DCT	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74AVCH2T45DCUR	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74AVCH2T45DCUT	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74AVCH2T45YZPR	ACTIVE	DSBGA	YZP	8	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

PACKAGE OPTION ADDENDUM



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Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and package die adhesive used between the die and package die adhesive used between the die adhesive used between the die adhesive use

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION

REEL DIMENSIONS

TEXAS INSTRUMENTS





TAPE AND REEL INFORMATION

TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AVCH2T45DCUR	US8	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74AVCH2T45YZPR	DSBGA	YZP	8	3000	180.0	8.4	1.02	2.02	0.63	4.0	8.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

18-Feb-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AVCH2T45DCUR	US8	DCU	8	3000	202.0	201.0	28.0
SN74AVCH2T45YZPR	DSBGA	YZP	8	3000	220.0	220.0	34.0

MECHANICAL DATA

MPDS049B - MAY 1999 - REVISED OCTOBER 2002

DCT (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion

D. Falls within JEDEC MO-187 variation DA.



DCT (R-PDSO-G8) PLASTIC SMALL OUTLINE Example Board Layout Example Stencil Design (Note C,E) (Note D) - 6x0,65 - 6x0,65 8x0,25-8x1,55 3,40 3,40 Non Solder Mask Defined Pad Example Pad Geometry -0,30 (Note C) 1,60 Example -0,07 Non-solder Mask Opening All Around (Note E) 4212201/A 10/11

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-187 variation CA.



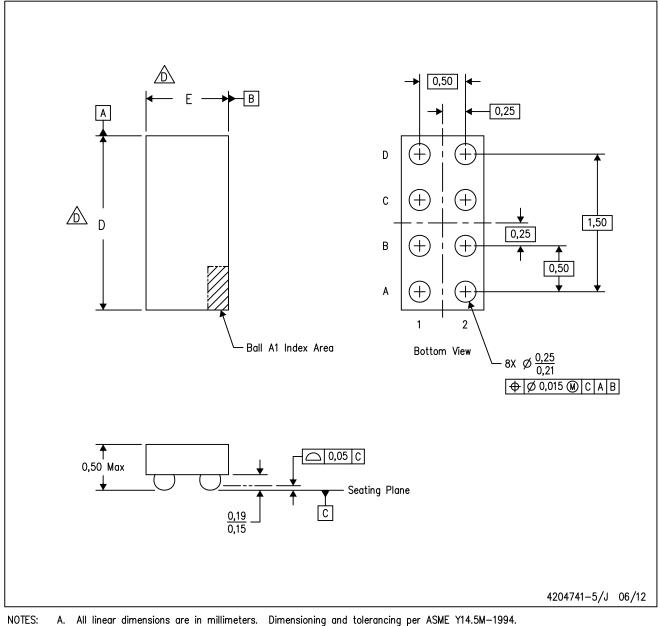


- NOTES: A. All linear dimensions are in millimeters. В. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



YZP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- The package size (Dimension D and E) of a particular device is specified in the device Product Data Sheet version of this drawing, in case it cannot be found in the product data sheet please contact a local TI representative.
 E. This package is a Pb-free solder ball design. Refer to the 8 YEP package (drawing 4204725) for tin-lead (SnPb).

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